NSN 5961-01-304-5442

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View Online at https://aerobasegroup.com/nsn/5961-01-304-5442 **Inclosure Material:** Metal **Overall Length:** 0.975 inches **Overall Height:** 0.210 inches **Overall Width:** 0.650 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Slot **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage, dc with base short-circuited to emitter and 32.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current and 750.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 32.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads and flange plated gold **Test Data Document:** 31550-515538 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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